TAIWAN SEMICONDUCTOR

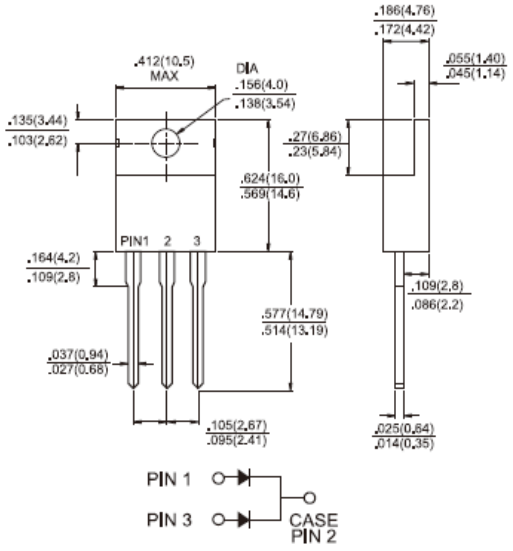
RoHS COMPLIANCE

SF2001G- SF2008G

20.0AMPS. Glass Passivated Super Fast Rectifiers

TO-220AB





Features

- ✧ High efficiency, low VF
- ✧ High current capavility
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss.
- ✧ For use in low voltage, high frequency inventor, free wheeling, and polarity protection application
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ✧ Cases: TO-220AB Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ High temperature soldering guaranteed: 260°C/10 seconds 16".,(4.06mm) from case.
- ✧ Weight: 1.90 grams

Dimensions in inches and (millimeters)

Marking Diagram



SF200XG	= Specific Device Code
G	= Green Compound
Y	= Year
WW	= Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 ℃ ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	SF 2001G	SF 2002G	SF 2003G	SF 2004G	SF 2005G	SF 2006G	SF 2007G	SF 2008G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	20								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150								A
Maximum Instantaneous Forward Voltage (Note 1) @ 10 A	V_F	0.975				1.3		1.7		V
Maximum DC Reverse Current @ T_A=25 ℃ at Rated DC Blocking Voltage @ T_A=125 ℃	I_R	5 400								uA
Maximum Reverse Recovery Time (Note 2)	Trr	35								nS
Typical Junction Capacitance (Note 3)	Cj	80								pF
Typical Thermal Resistance	$R_{\theta JC}$	2.5								°C/W
Operating Temperature Range	T_J	- 55 to + 150								°C
Storage Temperature Range	T_{STG}	- 55 to + 150								°C

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A.

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (SF2001G THRU SF2008G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

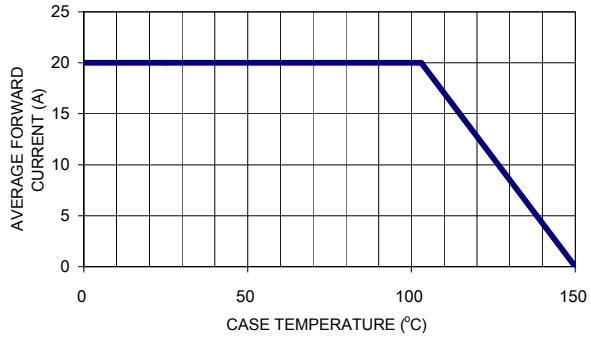


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

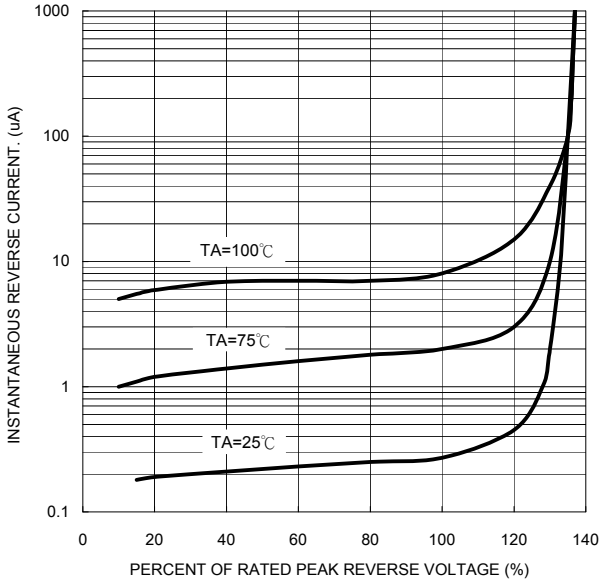


FIG. 3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

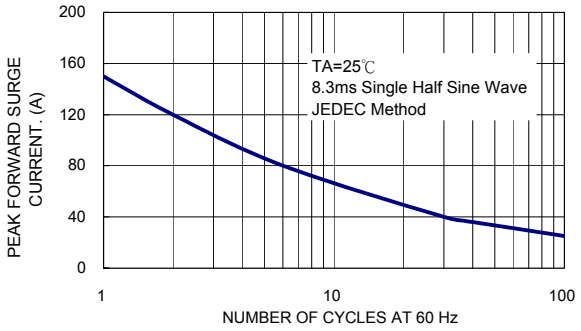


FIG. 5- TYPICAL FORWARD CHARACTERISRICS PER LEG

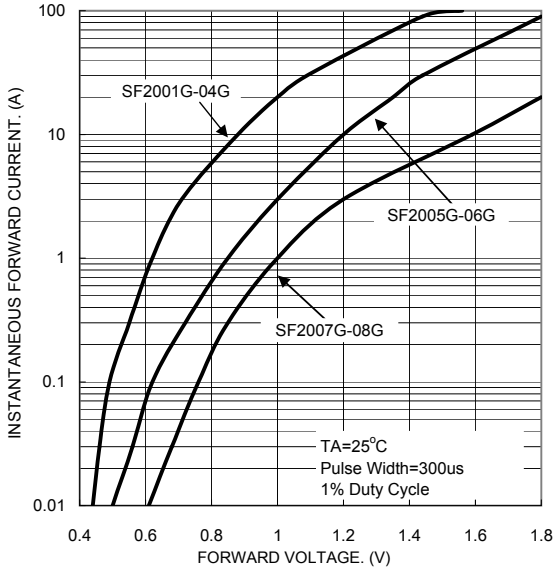


FIG. 4- TYPICAL JUNCTION CAPACITANCE PER LEG

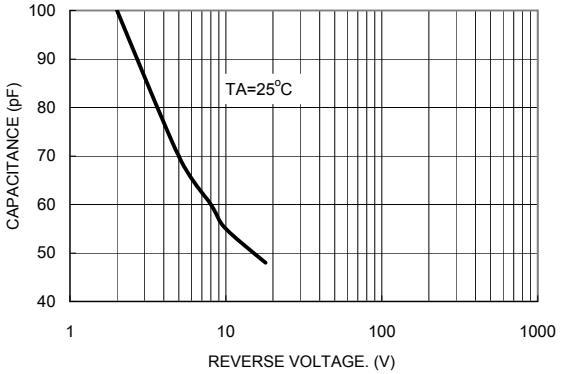


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

